NSN 5961-01-316-1761

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-316-1761 **Inclosure Material:** Plastic **Overall Length:** 0.625 inches **Overall Height:** 0.190 inches **Overall Width:** 0.420 inches **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-220 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 1000.0 drain to gate voltage and 1000.0 drain to source voltage and 20.0 gate to source voltage **Current Rating Per Characteristic:** 6.00 amperes off-state current, peak **Power Rating Per Characteristic:** 75.0 watts total device dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No